1.0A STANDARD DIODE

Features

- Diffused Junction
- Low Forward Voltage Drop
- High Current Capability
- High Reliability
- High Surge Current Capability

Mechanical Data

Case: R-1, Molded Plastic

Terminals: Plated Leads Solderable per

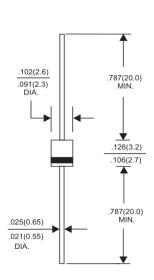
MIL-STD-202, Method 208

Polarity: Cathode Band

Weight: 0.181 grams (approx.)

Mounting Position: AnyMarking: Type Number

Lead Free: For RoHS / Lead Free Version



R-1

Dimensions in inches and (millimeters)

Maximum Ratings and Electrical Characteristics @TA=25°C unless otherwise specified

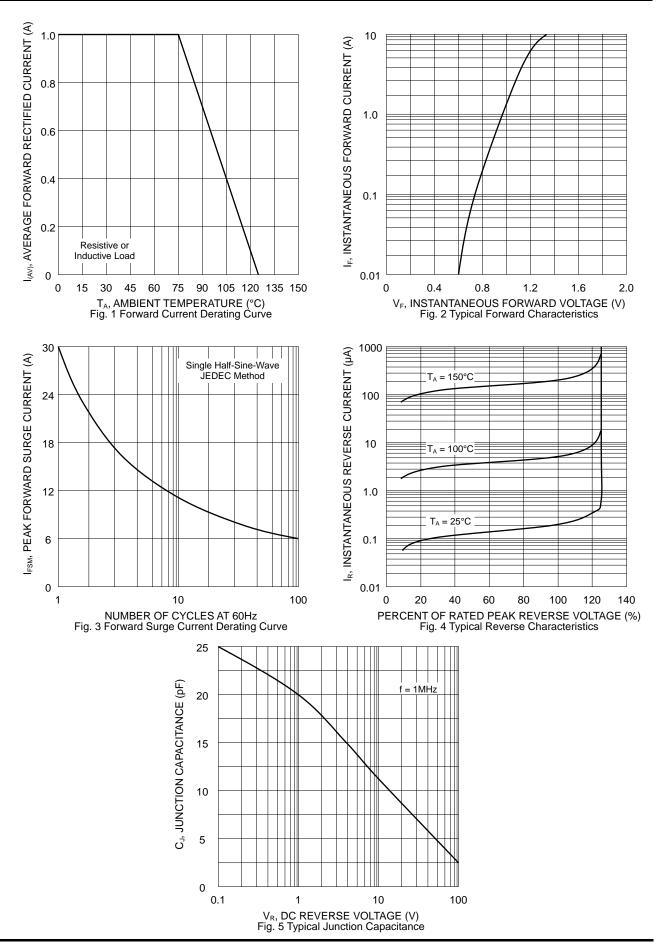
Single Phase, half wave, 60Hz, resistive or inductive load. For capacitive load, derate current by 20%.

Characteristic	Symbol	1A1	1A2	1A3	1A4	1A5	1A6	1A7	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	VRRM VRWM VR	50	100	200	400	600	800	1000	V
RMS Reverse Voltage	VR(RMS)	35	70	140	280	420	560	700	V
Average Rectified Output Current (Note 1) @T _A = 75°C	lo	1.0							Α
Non-Repetitive Peak Forward Surge Current 8.3ms Single Half Sine-Wave Superimposed on Rated Load (JEDEC Method)	IFSM	30							А
Forward Voltage @I _F = 1.0A	VFM	1.0						V	
	IRM	5.0 50							μΑ
Typical Junction Capacitance (Note 2)	Cı	15							pF
Typical Thermal Resistance Junction to Ambient (Note 1)	R JA	50							°C/W
Operating Temperature Range	TJ	-65 to +125							°C
Storage Temperature Range	Тѕтс	-65 to +150							°C

Note: 1. Leads maintained at ambient temperature at a distance of 9.5mm from the case.

2. Measured at 1.0 MHz and Applied Reverse Voltage of 4.0V D.C.

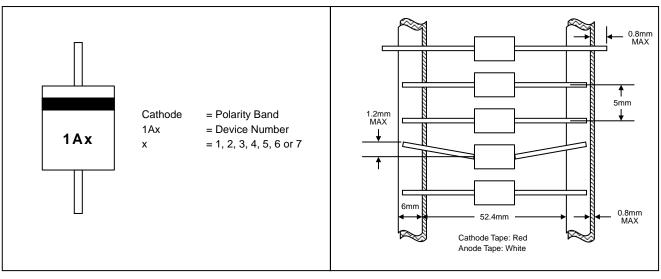






MARKING INFORMATION

TAPING SPECIFICATIONS



PACKAGING INFORMATION

